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Table of Contents

Section I. Surface, Films, Layers

Section Chair: Igor G. Neizvestny

1. Electrical Properties of MIS-Structures and Schottky Barriers of Si/GaAs (001) Interface	3-5
<i>Maxim S. Aksenov, Valery V. Preobrazhensky, Mikhail A. Putyato, Boris R. Semyagin, Natalya A. Valisheva, Oleg E. Tereshchenko</i>	
2. Self-Aligned Multilayer Dielectric “Dummy Gate” Technology for GaAs HFET Fabrication	6-9
<i>Vadim S. Arykov, Anastasia M. Gavrilova, Olga A. Dedkova, Valery A. Kagadei</i>	
3. Exploration of Optical and Electronic Parameters of Lithium Thiogallate (LiGaS₂)	10-14
<i>Victor V. Atuchin, Ludmila I. Isaenko, Valeriy G. Kesler, Zheshuai Lin, S.I. Lobanov</i>	
4. Formation of α-MoO₃ (010) Micropalettes for Nanoarchitecture	15-18
<i>Irina B. Troitskaia, Valery V. Atuchin, Tatiana A. Gavrilova, Dmitriy V. Sheglov</i>	
5. AFM Study of Atomic-Flat Terraces on ZnWO₄ (010) Cleaved Surface	19-22
<i>Anton S. Kozhukhov, Victor V. Atuchin, Evgeny N. Galashov, Vladimir N. Shlegel</i>	
6. Synthesis, Structural and Vibrational Properties of Rare-Earth Molybdates MNd(MoO₄)₂ (M=Rb, Tl) and TlPr(MoO₄)₂	23-26
<i>Victoria G. Grossman, Victor V. Atuchin, Bair G. Bazarov, Olga D. Chimitova, Tatiana A. Gavrilova, Zhibzema G. Bazarova, Nikolai V. Surovtsev</i>	
7. Nanoporous Rutile (TiO₂) Microspheres Formed in Water-Based Solution	27-29
<i>Irina B. Troitskaia, Tatiana A. Gavrilova, Victor V. Atuchin</i>	
8. Negative Dispersion in γ-Mo₂N/Si(100) Films	30-33
<i>Victor V. Atuchin, Tokhir Khasanov, Vasilii A. Kochubey, Lev D. Pokrovsky, Elena S. Senchenko</i>	
9. Formation of HfO₂/GaAs(001) Interface with Si Interlayer	34-36
<i>Vladimir A. Golyashov, Maxim S. Aksenov, Natalya A. Valisheva, Igor P. Prosvirin, Alexandr V. Kalinkin, Valery V. Preobrazhensky, Mikhail A. Putyato, Boris R. Semyagin, Oleg E. Tereshchenko</i>	
10. Effect of As₂ and As₄ Fluxes on the Morphology of GaSb(001) Surface During Growth of GaSb/InAs Heterojunction by MBE	37-40
<i>Eugene A. Emelyanov, Mikhail A. Putyato, Boris R. Semyagin, A. Vasilenko, D. Feklin, Andrey V. Vasev, Valery V. Preobrazhenskii</i>	
11. Copper Germanium Alloys Formation by Low Temperature Atomic Hydrogen Treatment	41-44
<i>Artyom I. Kazimirov, Evgeny V. Erofeev, Valery A. Kagadei</i>	
12. Effect of Magnetic Field on Injection Currents in PbSnTe:In Films	45-49
<i>Alexander E. Klimov, Vladimir N. Shumsky, Vladimir S. Epov, Boris I. Kidyarov</i>	
13. The Influence of Low-Temperature Annealing on Properties of Heterostructures p-HgCdTe Grown by Molecular-Beam Epitaxy	50-53
<i>Denis V. Kombarov, Dmitry Yu. Protasov, Vladimir Ya. Kostyuchenko</i>	
14. Prediction of Transparency and Non-linear Optical Susceptibility of Acentric Bismuthate Crystals	54-56
<i>Anton S. Korotkov</i>	
15. Graphene-N-methylpyrrolidone Based Hybrid Material: Tunable Structural and Electrical Properties	57-60
<i>Igor A. Kotin, Irina V. Antonova, Regina A. Soots, Vladimir A. Volodin, Victor Ya. Prinz</i>	
16. Features of Surface and Interface with Dielectric for Narrow-Gap A₃B₅ Semiconductors	61-62
<i>Georgy L. Kuryshv</i>	
17. MBE Compatible Surface Plasmon Resonance Technique Based on Droplet Epitaxy	63-65
<i>Anna A. Lyamkina, Sergey P. Moshchenko</i>	
18. Stability of (0001) Bi₂Te₃ Surface	66-67
<i>Sergey V. Makarenko, Viktor V. Atuchin, Konstantin A. Kokh, Vladimir A. Golyashov, Anton S. Kozhukhov, Igor P. Prosvirin, Oleg E. Tereshchenko</i>	
19. Investigation of SiO_x Layer Annealing Process Using Monte Carlo Simulation	68-72
<i>Eugene A. Mikhantiev, Alexander N. Karpov, Stanislav V. Usenkov, Natalia L. Shwartz</i>	
20. Use of Method for Chemical Etching for Identification of Structure of Proton Exchange Channel Waveguides Fabricated on Z-cut of Lithium Niobate Crystal	73-75
<i>Vladimir I. Kichigin, Sergey S. Mushinsky, Igor V. Petukhov, Denis I. Shevtsov, Anatoly B. Volyntsev</i>	

21. Microindentation of Proton Exchange Layers in Lithium Niobate Crystals	76-79
<i>Vladimir I. Kichigin, Igor V. Petukhov, Andrey P. Skachkov, Sergey S. Mushinsky, Denis I. Shevtsov, Anatoly B. Volyntsev</i>	
22. Hydrofluoric Acid Modifications of Graphene Films	80-82
<i>Nadezhda A. Nebogatikova, Irina V. Antonova, Victor Ya. Prinz</i>	
23. Photoluminescence of AlGaIn/GaN Heterostructures with Two-Dimensional Electron Gas and Unknown Acceptor Center	83-85
<i>Igor V. Osinnykh, Konstantin S. Zhuravlev, Timur V. Malin, Ivan A. Aleksandrov</i>	
24. Electrophysical Properties of Nonplanar Surfaces of Semiconductor Nanocomposite Materials	86-90
<i>Nikolay K. Poluyanovich, Artem N. Pritula, Marina N. Dubyago</i>	
25. Pyramid-Like Si Structures Grown on the Step Bunched Si(111)-(7×7) Surface	91-95
<i>Dmitry I. Rogilo, Lyudmila I. Fedina, Sergey S. Kosolobov, Alexander V. Latyshev, Bogdan S. Rangelov</i>	
26. Nanotexturing of Ceramic Products Surface by Means of Low-Energy Electron and Laser Exposure	96-99
<i>Elena V. Savruk, Seraphim V. Smirnov</i>	

Section II. Two-, One- and Zero-Dimensional Systems

Section Chair: Natalia L. Shwartz

1. Measurements of Photodiode Parameters in the Geiger Mode	103-104
<i>Vladimir L. Kurochkin, Aleksey A. Wolf</i>	
2. Formation of Complexes of Quantum Dots InAs and Nanoclusters As in Matrix GaAs by Molecular Beam Epitaxy	105-107
<i>Alexander A. Zaichenko, B. R. Semyagin, V.V. Preobrazhenskii, M.A. Putyato, V.N. Nevedomskii, V.V. Chaldyshev, N.A. Bert</i>	
3. Optimization of RHEED Observing Conditions of Quantum Dots by Numerical Simulation	108-110
<i>Dmitry M. Kazantsev, Yury G. Galitsyn</i>	
4. Monte Carlo Model of GaAs Nanowhisker Growth	111-113
<i>Maria V. Knyazeva, Alla G. Nastovjak, Nataliya L. Shwartz</i>	
5. Protocols for Quantum Cryptography	114-115
<i>Vladimir L. Kurochkin</i>	
6. Optimization of Surface Treatment of SOI-Nanowire Sensors	116-118
<i>Nikolay F. Malyarenko, Olga V. Naumova, Erdem D. Zhanaev, Vladimir P. Popov</i>	
7. Formation of Two-dimensional Photonic Crystals by Electron-beam Lithography	119-121
<i>Dmitry E. Utkin, Dmitry A. Nasimov</i>	

Section III. Semiconductor Devices

Section Chair: Victor A. Gridchin

1. Buck and Boost Converter Design Optimization Parameters in Modern VLSI Technology	125-128
<i>S. M. Asif Iqbal, Saad Mekhilef, Norhayati Soin, Rosli Omar</i>	
2. Bolometer at Semiconductor-Metal Phase Transition in VO₂ Thin Films	129-131
<i>Vladimir Sh. Aliev, Sergey G. Bortnikov</i>	
3. Dynamic Current Localization in Power Bipolar Switches with Imperfect Interconnections of Controlled Cells	132-136
<i>Dmitriy V. Gusin, Andrew V. Gorbatyuk, Igor V. Grekhov</i>	
4. Model of Effect of PN-Junction Magnetic Field Modulation	137-139
<i>Anton V. Kozlov, Andrey A. Cheremisinov, Sergey A. Polomoshnov, Robert D. Tikhonov, Sergey V. Shamanaev</i>	
5. Gamma Radiation Response for SOI MOSFETs Fabricated on DeleCut and Unibond Wafers	140-142
<i>Elza G. Kulubaeva, Olga V. Naumova, Michael A. Ilnitsky, Vladimir P. Popov</i>	
6. Power Consumption Reduction for Configuration SRAM of Field Programmable Gate Arrays	143-145
<i>Denis V. Matyushin, Sergei I. Kurganskii</i>	

7. The Formation of Multilayer Resist Mask for Transistor T-gates Fabrication Using Electron-Beam Lithography	146-149
<i>Ekaterina V. Anishchenko, Evgeny V. Erofeev, Sergey V. Ishutkin, Valery A. Kagadei, Ksenia S. Nosaeva</i>	
8. Electrical Microchannel Silicon Sensor for Solvent Detection	150-151
<i>Maksim A. Parashchenko, Natalia V. Vandisheva, Victor V. Kirienko, Nikolay S. Filippov, Sergey I. Romanov</i>	
9. Reduction of Offset in Pressure Sensors with Polysilicon Piezoresistors by the Pulse Current Annealing Method	152-154
<i>Anton V. Polstyankin, Victor A. Gridchin</i>	
10. Technological Factors Having Effect on Calibration of Beam Heat Flux Sensor	155-159
<i>Mariya N. Polyashchenkova, Mikhail A. Chebanov, Oleg V. Lobach</i>	
11. Device for Video Recording and Analysis of Galloping Processes	160-161
<i>Alexander N. Samsonov, Fedor A. Bykovskiy</i>	
12. Analysis of Certain Methods for Determining Contact Resistivity	162-164
<i>Ivan A. Smirnov, Sergey V. Kalinin</i>	
13. Development of Self-aligned T-Gate pHEMT Technology	165-167
<i>Maria A. Fedosova, Anastasia M. Gavrilova, Evgeny V. Erofeev, Vadim S. Arykov</i>	
14. Use of Self-Aligned Technology in GaAs Scotty Diode Fabrication	168-170
<i>Igor V. Yunusov, Anastasiya M. Gavrilova, Vadim S. Arykov</i>	

Section IV. Telecommunications and Communication Networks

Section Chair: Sergey I. Solovyev

1. Estimation of RF Propagation Channel Transfer Function with Consideration about Its Priori Structure	173-178
<i>Alexander S. Vershinin, Eugeny P. Voroshilin, Eugeny V. Rogozhnikov, Denis Y. Maikov</i>	
2. Experimental Estimation of Accuracy Enhancement of TOA Measurement by Communication System in Case Of Multichannel Processing	179-182
<i>Alexander S. Vershinin, Eugeny P. Voroshilin, Eugeny V. Rogozhnikov, Dmitry A. Korotkov, Denis Y. Maikov</i>	
3. Comparison of Algorithms for Construction of Logical Channels for Secondary Subscribers	183-185
<i>Oleg G. Melentyev, Nikita V. Lyamin, Denis V. Kleiko</i>	
4. Phase-Shift Keying Device Based On Tunable Filter	186-188
<i>Artem A. Abrosimov, Vladimir P. Razinkin</i>	
5. Methods for Increase in Transmission Distance of Single Photons in Communication Lines	189-190
<i>Dmitry S. Rakuta, Sergey Y. Anufriev, Boris I. Kidyarov, Vladimir L. Kurochkin, Igor I. Ryabtsev, Alexander G. Cherevko, Igor Y. Yakushev</i>	
6. Development and Investigation of Microstrip Directional Coupler with Phase Velocity Compensation Based on Sawtooth Configuration of Coupled Lines	191-194
<i>Alexander A. Shauerman, Alexander V. Borisov, Mikhail S. Zharikov, Ainur K. Shauerman, Fedor S. Kroshin</i>	
7. Simulator of Transmitter Portion of Single-Photon Communication Line	195-198
<i>Alexander G. Cherevko, Viktor N. Naumov, Alexander V. Borisov, Alexander A. Shauerman, Nikita V. Popov, Mikhail S. Zharikov</i>	
8. Simulator of Receiver Portion of Single Photon Cryptographic Communication Line in LabVIEW	199-202
<i>Alexander G. Cherevko, Viktor N. Naumov, Alexander V. Borisov, Alexander A. Shauerman, Nikita V. Popov, Mikhail S. Zharikov</i>	

Section V. Wireless Communications

Section Chair: Elena V. Bezuglaya

1. Linux-Based Test-Bed for Testing of QoS Subsystems in Broadband Wireless Networks	205-208
<i>Ivan V. Boichenko, Evgeniy V. Bortnikov</i>	

Session VI. Television and Radio Broadcasting Systems, Antennas and Data Communication

Section Chair: Alexander V. Borisov

- | | |
|---|----------------|
| 1. Features of the Practical Realization of the Generating Filter of the Digital Transmitter | 211-213 |
| <i>Alexander V. Mikushin, Vladimir B. Sholskiy</i> | |
| 2. Broadband Attenuator | 214-216 |
| <i>Vadim S. Churkin, Michael G. Rubanovich, Vladimir P. Razinkin</i> | |

Section VII. Microwave Theory and Technology

Section Chair: Georgiy L. Kuryshv

- | | |
|---|----------------|
| 1. Microwave-Induced Giant Oscillations of the Magnetoconductivity and Zero-Conductance State in 2D Electronic Corbino Disks with Capacitance Contacts | 219-221 |
| <i>Dmitriy V. Dmitriev, Igor V. Marchishin, Andrey V. Goran, Alexey A. Bykov</i> | |

Section VIII. Sound and Ultrasound devices: Physics, Electronics, Applications

Section Chair: Vladimir N. Khmelev

- | | |
|--|----------------|
| 1. Compact Ultrasonic Drier for Low Temperature Dehydration of Products in Food Industry | 225-229 |
| <i>Vladimir N. Khmelev, Anton N. Galakhov, Andrey V. Shalunov, Maxim V. Khmelev</i> | |
| 2. Development of Equipment for Ultrasonic Defoaming and Determination of its Functional Capabilities | 230-235 |
| <i>Vladimir N. Khmelev, Anton N. Galakhov, Andrey V. Shalunov, Andrey A. Romashkin</i> | |
| 3. Method of Acoustic Load Control | 236-240 |
| <i>Vladimir N. Khmelev, Roman V. Barsukov, Dmitry V. Genne, Denis S. Abramenko, Eugene V. Ilchenko</i> | |
| 4. Practical Investigations of the Method for Indirect Control of Acoustic Load Parameters | 241-244 |
| <i>Vladimir N. Khmelev, Roman V. Barsukov, Dmitry V. Genne, Denis S. Abramenko, Eugene V. Ilchenko, Andrey V. Shalunov</i> | |
| 5. Method for Calculation of Optimum Intensity of Cavitation Influence on Viscous and Fine-dispersed Liquid Media | 245-250 |
| <i>Vladimir N. Khmelev, Roman N. Golykh, Sergey S. Khmelev, Roman V. Barsukov</i> | |
| 6. Process Modeling of Cavitation Zone in Process Vessels with High-viscous and Fine-dispersed Liquid Media | 251-256 |
| <i>Roman N. Golykh, Vladimir N. Khmelev, Sergey S. Khmelev</i> | |
| 7. Increase in Phytotoxicity of N-Phosphonomethyl-glycine during Ultrasonic Atomization with Ultralow Doses of Organic Acids | 257-259 |
| <i>Alexander L. Verestchagin, Julia I. Zakharieva, Vladimir N. Khmelev</i> | |
| 8. Increase in Efficiency of Operation of Ultrasonic Processing Devices (Based on Welding of Thin Sheets) | 260-264 |
| <i>Roman V. Barsukov, Denis S. Abramenko, Evgeny V. Ilchenko</i> | |
| 9. Studying of Ultrasonic Treatment Effect on Sea-Buckthorn Wine Clarification | 265-268 |
| <i>Vladimir N. Khmelev, Sergey N. Tsyganok, Roman V. Barsukov, Valery P. Sevodin, Eugene D. Rozhnov, Yuriy M. Kuzovnikov, Denis S. Abramenko</i> | |
| 10. Application of Ultrasonic Processing Devices in Liquefaction of Candied Honey | 269-271 |
| <i>Vladimir N. Khmelev, Sergey N. Tsyganok, Roman V. Barsukov, Yuriy M. Kuzovnikov, Denis S. Abramenko</i> | |
| 11. Application of Ultrasound for Production of the Heat-insulated Floor Elements | 272-274 |
| <i>Vladimir N. Khmelev, Sergey N. Tsyganok, Sergey S. Khmelev, Sergey V. Levin</i> | |
| 12. Increase in Efficiency of Processes through Optimization of Ultrasonic Vibrating System Consisting of Half-Wave Modules of Variable Cross-Section | 275-280 |
| <i>Vladimir N. Khmelev, Sergey V. Levin, Sergey N. Tsyganok, Sergey S. Khmelev</i> | |

13. Influence of Surface Friction on Continuous Ultrasonic Welding of Thin Polymer Films	281-284
<i>Andrew V. Lehr, Vladimir N. Khmelev, Viktor A. Nesterov, Aleksey N. Slivin</i>	
14. Elaboration of Continuous Wavelet Transform Parameters for Problems of Ultrasonic Thickness Gauging	285-287
<i>Valery G. Efimov, Julia N. Lozhkova</i>	
15. Research of Transformation of Longitudinal Ultrasonic Vibrations into Radial Ones	288-291
<i>Viktor A. Nesterov, Vladimir N. Khmelev, Aleksey N. Slivin, Andrew V. Lehr</i>	
16. Method for Research of Pulsation Dynamics of Gas-Vapor Bubbles in Cavitation Process Initiated By Acoustic Oscillations	292-294
<i>Ekaterina I. Parfutchik, Igor I. Savin, Yuri A. Galenko</i>	
17. Ultrasonic Drying of Birch Veneer	295-299
<i>Vladimir N. Khmelev, Sergey S. Khmelev, Sergey N. Tsyganok, Gennadiy A. Titov</i>	
18. Experimental Researches of Asymmetric Parametrical System of Nonlinear Resonator in Higher Zones of Oscillation Instability	300-304
<i>Larissa V. Cherkesova, Alexander N. Zaichenko</i>	
19. Ultrasonic Atomizers of Nanomaterials	305-309
<i>Vladimir N. Khmelev, Andrey V. Shalunov, Maxim V. Khmelev, Anna V. Shalunova, Dmitry V. Genne</i>	

Section IX. Optical and Thermal Devices: Physics, Electronics, Applications

Section Chair: Evgeniy V. Sypin

1. Nanotechnologies in Development of Solar Cells	313
<i>Igor G. Neizvestny</i>	
2. Development of Ignition Center Detector with Possibility of Adaptation for Change in Gas-Dispersion Intermediate Environment	314-315
<i>Ekaterina V. Berestova, Sergey A. Terentiev, Eugene V. Sypin</i>	
3. The Facility for Experimental Explosions of Gas Mixtures with Possibility to Register Burning Parameters	316-320
<i>Denis V. Gerasimov, Eugene V. Sypin</i>	
4. Monitoring of Objects Hidden from Observation by Stray Lighting	321-326
<i>Fedor A. Gubarev, Gennadiy S. Evtushenko, Maxim V. Trigub, Stanislav N. Torgaev</i>	
5. Micromechanical IR-Systems	327-329
<i>Georgy L. Kuryshev</i>	
6. Scanning Infrared Microscope	330-332
<i>Ivan V. Mzhelskiy, Vladimir G. Polovinkin</i>	
7. Hardware-Based Elimination of Chatters for Amplification Range Switching Elimination in Pyrometric Devices of Two Spectral Ratios	333-335
<i>Evgeniy S. Povernov, Nadezhda Y. Tupikina, Eugene V. Sypin</i>	
8. Relaxation Processes of Mobile Charges in Integrated Optics Mach-Zehnder Interferometer	336-338
<i>Roman S. Ponomarev, Anton A. Zhuravlev, Alexander V. Kichanov</i>	
9. Plant for Research of Parameters of Optoelectronic Detectors for Detection of Dust-Gas-Air Mixture Explosions	339-342
<i>Anton I. Sidorenko, Andrey N. Pavlov, Eugene V. Sypin</i>	
10. Method for Increase in Sensitivity of the Ignition Center Coordinate Pyrometric Detector	343-345
<i>Sergey A. Terentiev, Dmitriy A. Gerasimov, Eugene V. Sypin</i>	
11. LED Lighting	346-348
<i>Nikolay N. Bakin, Vasily I. Tuyev, Eduard F. Yauk</i>	
12. Development of the Technique for Selection of Operating Spectral Bands for Three-Channel Pyrometric Device of Two Spectral Ratios	349-353
<i>Nadezhda Y. Tupikina, Eugene V. Sypin</i>	
13. The Optical System for the Three-channel Pyrometric Device of Two Spectral Ratios	354-361
<i>Eugene V. Sypin, Nadezhda Y. Tupikina, Evgeniy S. Povernov</i>	
14. Comparative Analysis of Gas-Dispersed Media Burning Models	362-367
<i>Irina A. Uskova, Andrey N. Pavlov, Evgeniy V. Sypin</i>	
15. Scattering of Optical Radiation in Coal Mines	368-369
<i>Oksana Y. Yakusheva, Eugene V. Sypin</i>	

Section X. Power Electronics
Section Co-Chair: Sergey A. Kharitonov

<p>1. Modeling of Dual Z-Source Inverter for Aircraft Power Generation <i>Aleksey S. Khlebnikov, Sergey A. Kharitonov, Peter A. Bachurin, Andrei V. Geist, Denis V. Makarov</i></p> <p>2. Development and Research of Three-phase Multizone AC-DC Converters <i>Alexander G. Volkov, Gennady S. Zinoviev</i></p> <p>3. The Family of Matrix Converters <i>Vladimir Popov, Timofey Zhelonkin, Aleksey Gezha, Anton Grebnev</i></p> <p>4. Mining Starting Unit Based on Semiconductor Electric Power Converter <i>Andrei V. Geist, Aleksey S. Khlebnikov, Sergey A. Kharitonov, Peter A. Bachurin, Denis V. Makarov</i></p> <p>5. PWM Current Controller Design for Multi-level DC-DC Converter via Singular Perturbation Technique <i>Valery D. Yurkevich, Gennady S. Zinoviev, Artem A. Gordeev</i></p> <p>6. Development and Research of Bidirectional Step-Down AC-AC-DC Converter for AC Electric Locomotive <i>Daniil S. Kovelin, Gennady S. Zinoviev</i></p> <p>7. Three-Phase Transformerless Boost Multilevel Inverter with One DC Voltage Source <i>Nikolay N. Lopatkin</i></p> <p>8. New PWM Methods with Deterministic Change of Carrier Frequency <i>Igor A. Bakhovtsev, Aleksey K. Rakitin</i></p> <p>9. Studying of Solid-state Power Supply Unit of CuBr-Laser <i>Stanislav N. Torgaev, Maxim V. Trigub, Fedor A. Gubarev</i></p> <p>10. New Energy Saving Multizone Alternating-Voltage Soft Starters of Induction Machines <i>Alexei V. Udovichenko</i></p> <p>11. Energy-Efficient Secondary Power Supply Source for Light-Emitting Diode Display Devices <i>Vadim D. Khrenov, Igor I. Savin</i></p>	<p>373-376</p> <p>377-380</p> <p>381-385</p> <p>386-389</p> <p>390-398</p> <p>399-401</p> <p>402-405</p> <p>406-410</p> <p>411-414</p> <p>415-419</p> <p>420-421</p>
INDEX OF AUTHORS	423-425